

### Description

The DFI150HF17DF1 offer lower losses and higher energy for soft switching applications.



### Features

- 1700V150 A,  $V_{CE(sat)}(typ.) = 2.50V$
- Lower losses and higher energy
- Excellent short-circuit capability
- 62mm half bridge module

### Applications

- Motor drive
- Inverter
- Power supply
- Wind Turbines

### Circuit diagram

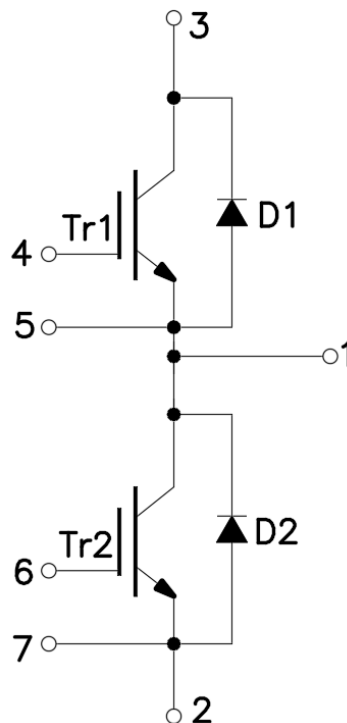


Figure 1. Out drawing & circuit diagram for DFI150HF17DF1

## Pin Configuration and Marking Information

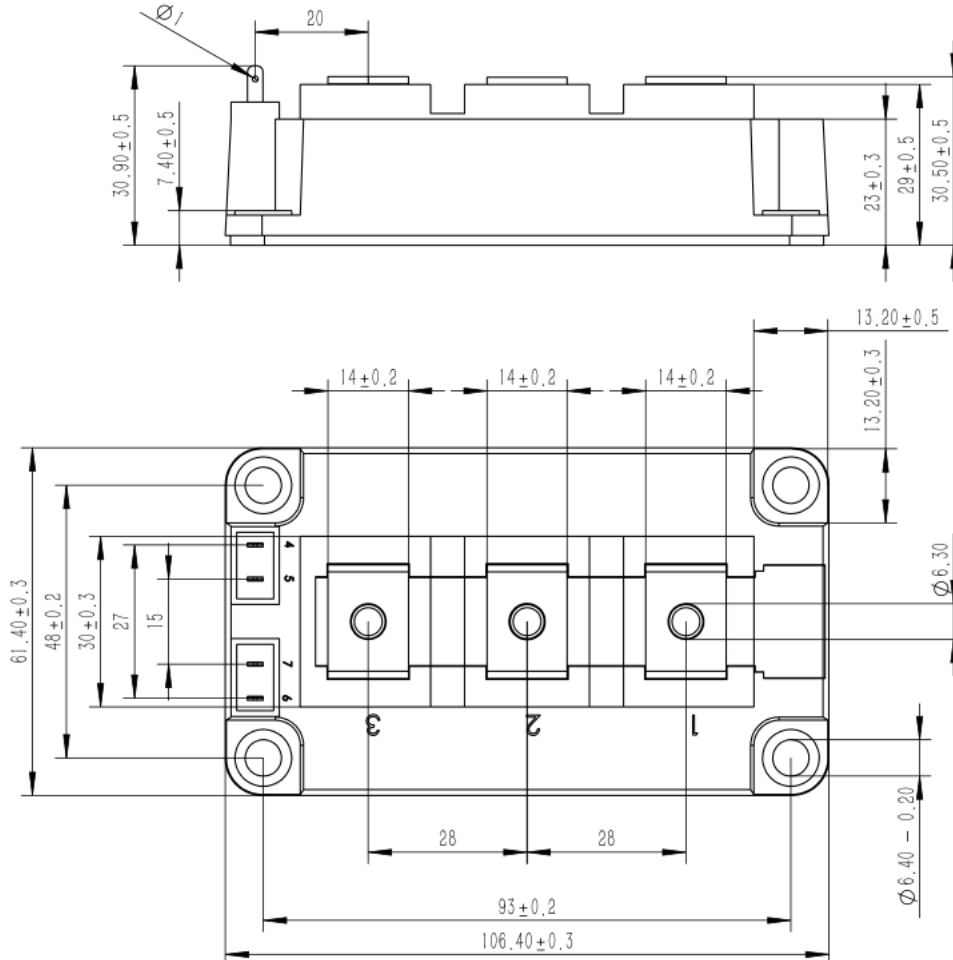


Figure 2. Pin configuration

## Module

Parameter	Conditions	Value	Unit
Isolation Voltage	RMS, f = 50Hz, t = 1min	4.0	KV
Material of module baseplate	-	Cu	-
Creepage distance	terminal to heatsink terminal to terminal	47 26	mm
Clearance	terminal to heatsink terminal to terminal	29 14	mm
CTI	-	>200	-
Module lead resistance, terminals – chip	T <sub>C</sub> = 25°C	0.8	mΩ
Mounting torque for module mounting	M6	3 to 6	Nm
Weight	-	315	g

### Maximum Ratings (IGBT, $T_j=25^{\circ}\text{C}$ unless otherwise specified)

Symbol	Parameter	Conditions	Ratings	Unit
$V_{CES}$	Collector-Emitter Voltage	G-E Short	1700	V
$V_{GES}$	Gate-Emitter Voltage	C-E Short	$\pm 30\text{V}$	V
$I_C$	DC Continuous Collector Current	$T_C=100^{\circ}\text{C}$	150	A
$I_{CM}$	Pulse Collector Current	$t_p=1\text{ms}$ , Note1	300	A
$P_C$	Maximum Power Dissipation	$T_C=25^{\circ}\text{C}$ , $T_j=150^{\circ}\text{C}$ (IGBT)	850	W
$T_{jop}$	junction temperature	-	-40 to 150	$^{\circ}\text{C}$
$T_{stg}$	Storage temperature	-	-40 to 125	$^{\circ}\text{C}$

Note1: Pulse width limited by maximum junction temperature

### Maximum Ratings (Freewheeling diode, $T_j=25^{\circ}\text{C}$ unless otherwise specified)

Symbol	Parameter	Conditions	Ratings	Unit
$V_{RRM}$	Peak Repetitive Revers Voltage	-	1700	V
$I_F$	Diode forward Current	- $T_C=100^{\circ}\text{C}$	150	A
$I_{FRM}$	Repetitive peak forward Current	$t_p=1\text{ms}$ , Note1	300	A
$T_{jop}$	junction temperature	-	-40 to 150	$^{\circ}\text{C}$
$T_{stg}$	Storage temperature	-	-40 to 125	$^{\circ}\text{C}$

Note1: Pulse width limited by maximum junction temperature

### IGBT Electrical characteristics ( $T_j=25^{\circ}\text{C}$ unless otherwise specified, chip)

Symbol	Item	Condition		Value			Unit
				Min.	Typ.	Max	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C=150\text{A}$ $V_{GE}=15\text{V}$	$T_j=25^{\circ}\text{C}$	-	2.50	2.70	V
			$T_j=125^{\circ}\text{C}$	-	2.80	3.0	V
$V_{GE(th)}$	Gate-Emitter threshold Voltage	$I_C=1\text{mA}$ , $V_{CE}=V_{GE}$		4.5	-	5.7	V
$Q_G$	Gate charge	$V_{GE}=-15\text{V}$ to $+15\text{V}$		-	1600	-	nC
$R_{Gint}$	Internal gate resistor	$f=1\text{M}$ , $V_{pp}=1\text{V}$	$T_j=25^{\circ}\text{C}$	-	3	-	$\Omega$
$C_{ies}$	Input Capacitance	$V_{CE}=25\text{V}$ , $V_{GE}=0\text{V}$ $f=1\text{MHz}$	$T_j=25^{\circ}\text{C}$	-	13	-	nF
$C_{oes}$	Output Capacitance			-	1.4	-	nF
$C_{res}$	Reverse transfer Capacitance			-	0.9	-	nF
$I_{CES}$	Collector- Emitter Cut off Current	$V_{CE}=1700\text{V}$ , $V_{GE}=0\text{V}$	$T_j=25^{\circ}\text{C}$	-	-	5	mA
$I_{GES}$	Gate-Emitter Leakage Current	$V_{GE}=\pm 30\text{V}$ , $V_{CE}=0\text{V}$	$T_j=25^{\circ}\text{C}$	-	-	400	nA
$t_{d(on)}$	Turn-on delay time	$V_{CC}=900\text{V}$ $I_C=150\text{A}$ $R_G=5.1\Omega$ $V_{GE}=\pm 15\text{V}$ Inductive Load	$T_j=25^{\circ}\text{C}$	-	88	-	ns
			$T_j=125^{\circ}\text{C}$	-	95	-	
$t_r$	Rise time		$T_j=25^{\circ}\text{C}$	-	65	-	ns
			$T_j=125^{\circ}\text{C}$	-	58	-	
$t_{d(off)}$	Turn-off delay time	$T_j=25^{\circ}\text{C}$	-	450	-	ns	
		$T_j=125^{\circ}\text{C}$	-	520	-		

$t_f$	Fall time	$V_{CC} = 900V$ $I_C = 150A$	$T_j = 25^\circ C$	-	320	-	ns
			$T_j = 125^\circ C$	-	530	-	
$E_{on}$	Turn-on power dissipation	$R_G = 5.1\Omega$ $V_{GE} = \pm 15V$	$T_j = 25^\circ C$	-	25	-	mJ
			$T_j = 125^\circ C$	-	30	-	
$E_{off}$	Turn-off power dissipation	Inductive Load	$T_j = 25^\circ C$	-	30	-	mJ
			$T_j = 125^\circ C$	-	40	-	
$R_{th(j-c)}$	Thermal Resistance, Junction to Case (IGBT)		-	-	-	0.15	$^\circ C/W$

### Freewheeling Diode Electrical characteristics ( $T_j = 25^\circ C$ unless otherwise specified, chip)

Symbol	Item	Condition	Value			Unit	
			Min.	Typ.	Max		
$V_F$	Diode Forward Voltage	$I_F = 150A, V_{GE} = 0V$	$T_j = 25^\circ C$	-	2.7	3.0	V
			$T_j = 125^\circ C$	-	2.8	-	
$t_{rr}$	Diode Reverse Recovery Time	$I_F = 150A,$ $di/dt = 3300A/\mu s,$	$T_j = 25^\circ C$	-	100	-	nS
			$T_j = 125^\circ C$	-	160	-	
$I_{rr}$	Peak reverse recovery Current	$V_R = 900V,$ $V_{GE} = -15V$	$T_j = 25^\circ C$	-	120	-	A
			$T_j = 125^\circ C$	-	135	-	
$Q_{rr}$	Recovered charge		$T_j = 25^\circ C$	-	10	-	uC
			$T_j = 125^\circ C$	-	16	-	
$E_{rr}$	Reverse recovered energy		$T_j = 25^\circ C$	-	5	-	mJ
			$T_j = 125^\circ C$	-	9	-	
$R_{th(j-c)}$	Thermal Resistance, Junction to Case (Diode)		-	-	-	0.160	$^\circ C/W$

## Test Conditions

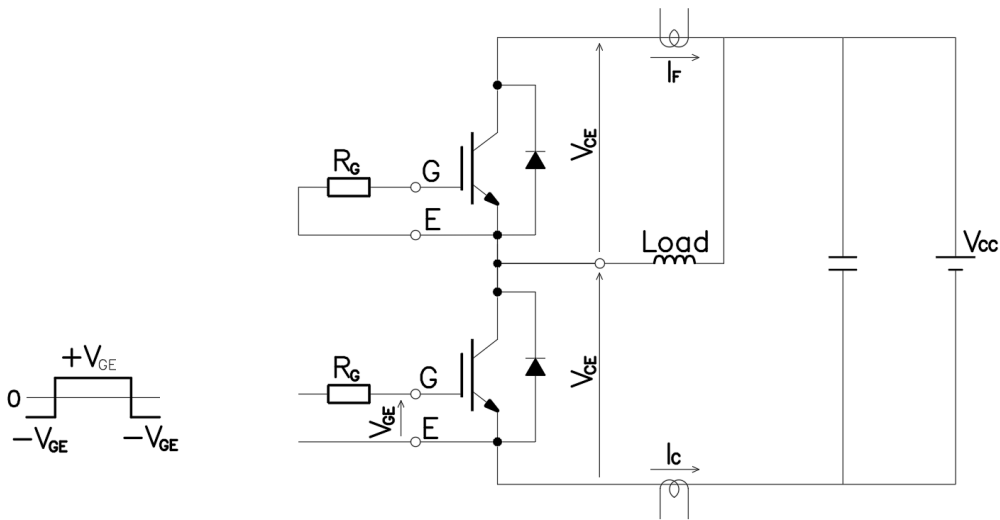


Figure 3. Switching time measure circuit

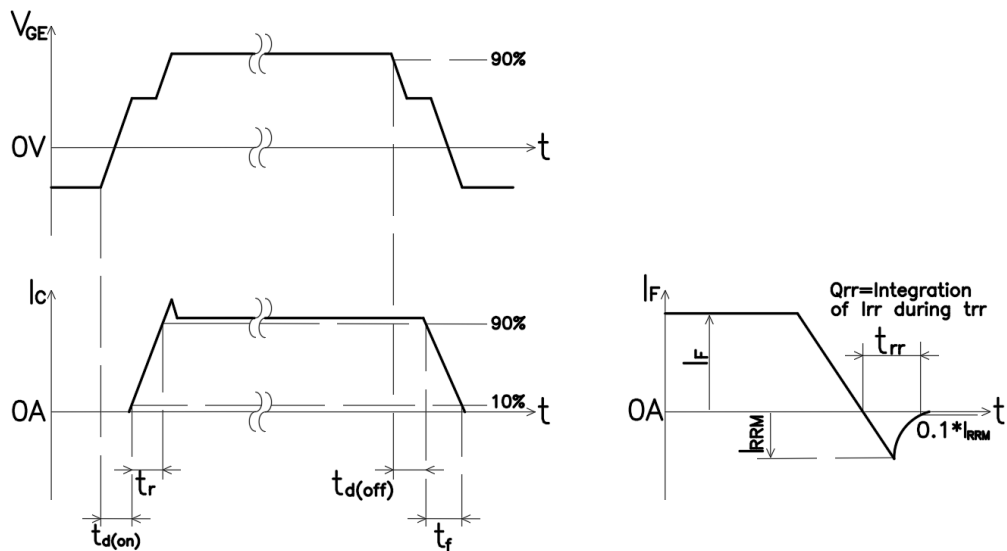


Figure 4. Switching time definition

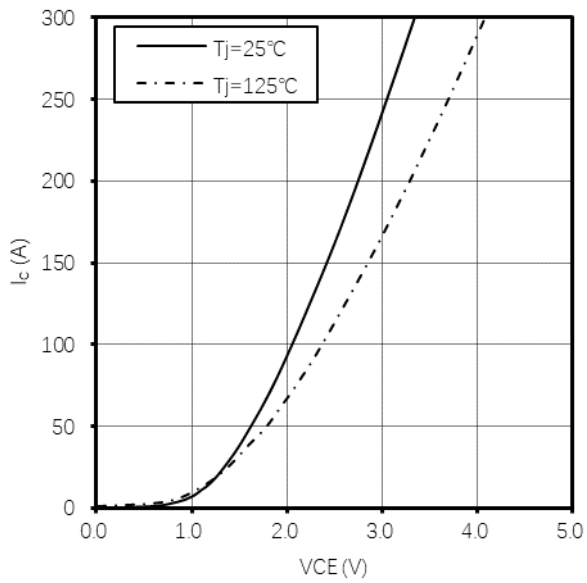


Figure 5.  $I_c$  vs  $V_{CE}$   
 $V_{GE} = 15\text{V}$

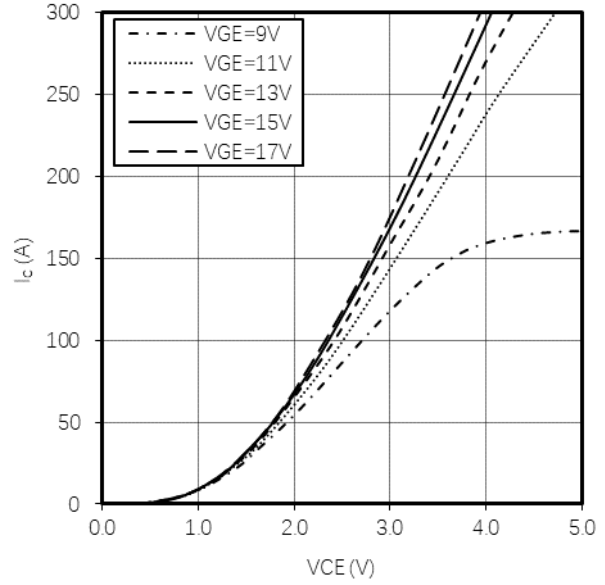


Figure 6.  $I_c$  vs  $V_{CE}$   
 $T_j = 125^\circ\text{C}$

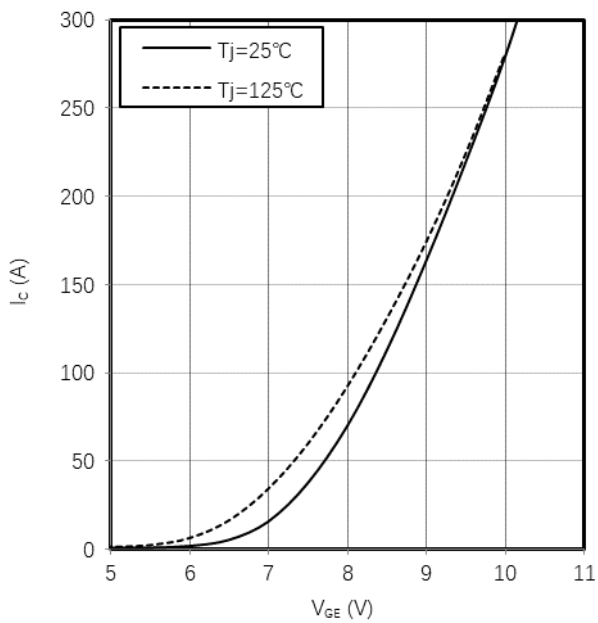


Figure 7.  $I_c$  vs  $V_{GE}$   
 $V_{CE} = 20\text{V}$

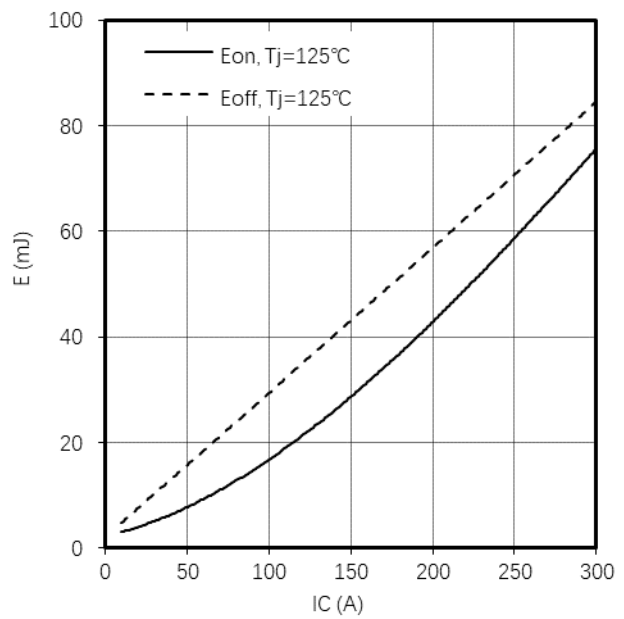


Figure 8.  $E_{on}$ ,  $E_{off}$  vs  $I_c$  (Typ)  
 $V_{CC} = 900\text{V}$ ,  $V_{GE} = +15\text{V}/-15\text{V}$ ,  $R_G = 5.1\Omega$

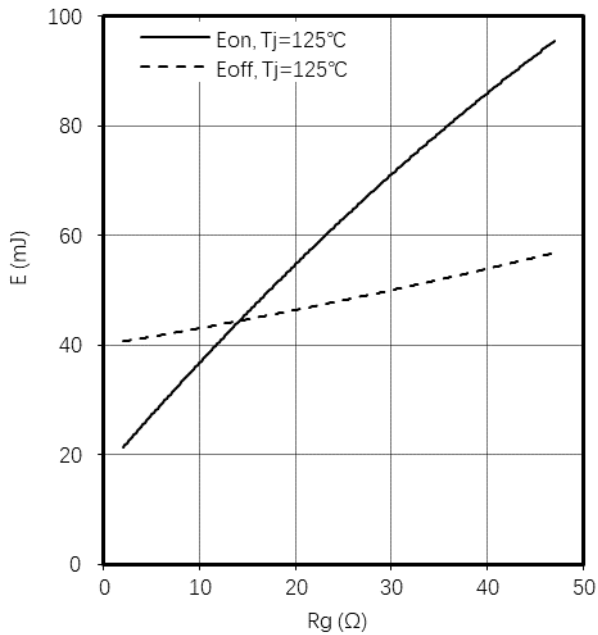


Figure 9.  $E_{on}$ ,  $E_{off}$  vs  $R_g$ (Typ)  
 $V_{CC}=900V$ ,  $V_{GE}=+15V/-15V$ ,  $I_C=150A$

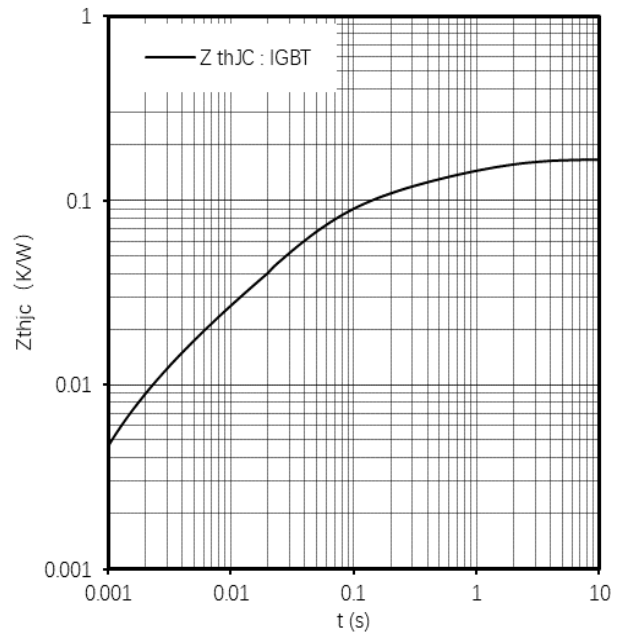


Figure 10. Transient thermal impedance IGBT ,  
 $Z_{thjc}=f(t)$

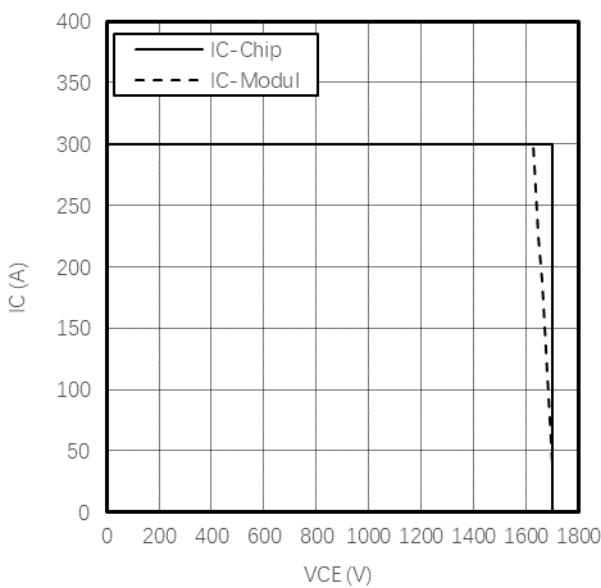


Figure 11. Reverse bias safe operating area IGBT,  
 $I_C=f(V_{CE})$ ,  $V_{GE}=\pm 15V$ ,  $R_{Goff}=5.1\Omega$ ,  $T_{vj}=125^\circ C$

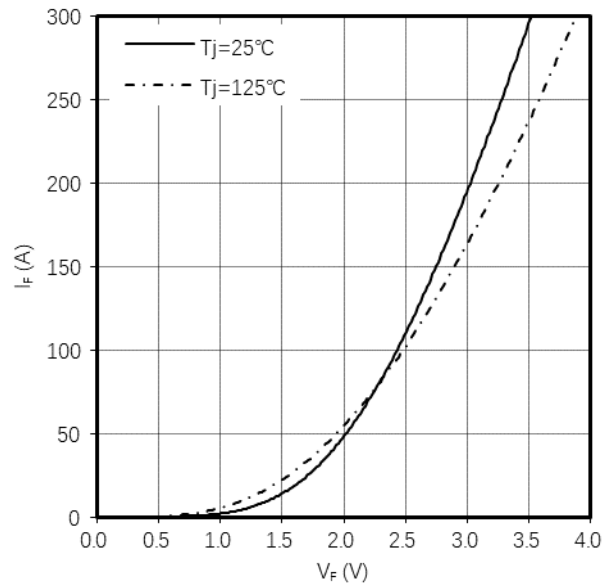
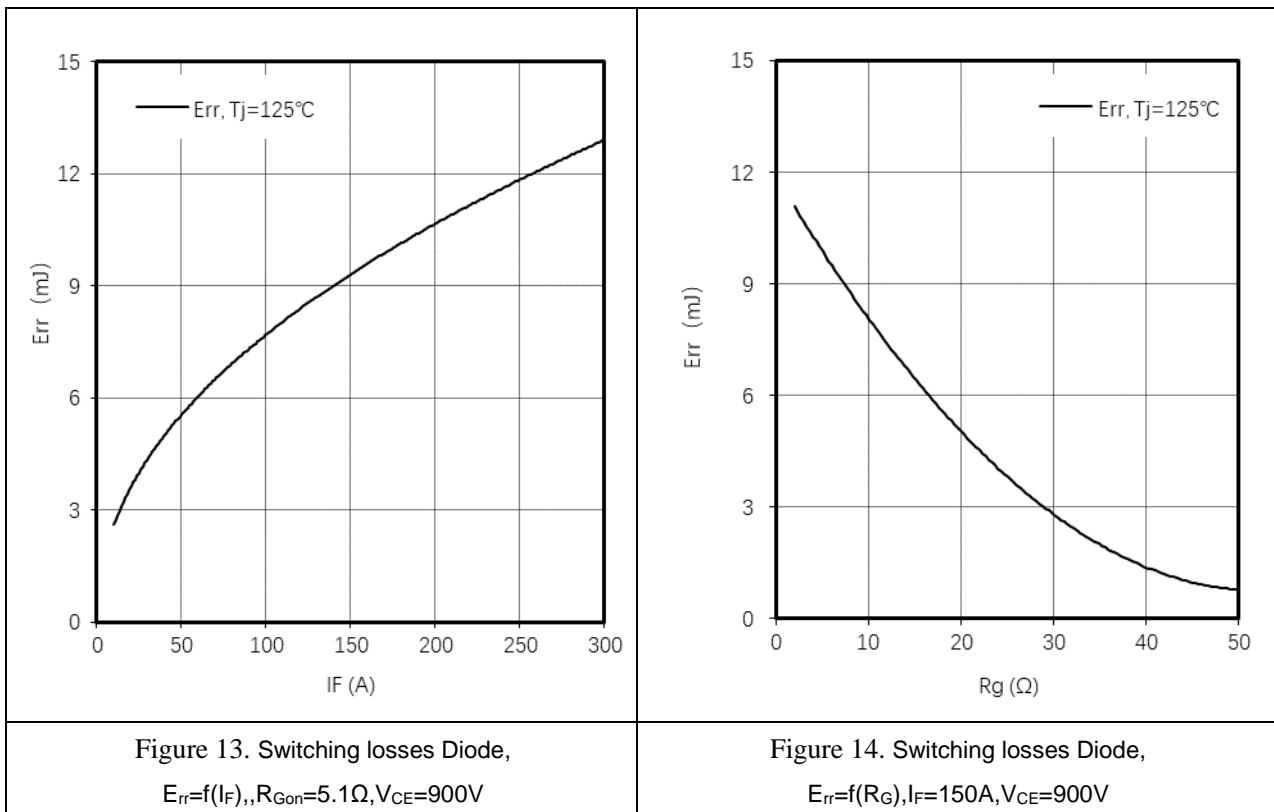


Figure 12. Forward characteristic of Diode ,  
 $I_F=f(V_F)$



### IMPORTANT NOTICE:

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The data contained in this document is exclusively intended for technically trained staff. You and your technical departments will have to evaluate the product's suitability for the intended application and the completeness of the product data concerning such application.

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